

Course name: EMI /EMC and Signal Integrity: Principles, Techniques and Applications.

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Lecture 52: SE Due to Farfield Sources (Continued) and Free Space Impedance At Nearfield

Welcome to the lecture of the course on EMIMC and Signal Integrity Principles, Techniques and Applications. We were discussing the shielding effectiveness due to far field sources in the last class. So, some portion is left. So, that we will continue then we will move on to the near field impedance descriptions. So, reflection loss I covered in the last class, absorption loss we have seen the expression of absorption loss. Let me see in a previous a we have seen that absorption loss is $20 \log_{10} e^{-t/\delta}$. So, that we will now put the material parameters in this expression. So, the first thing is skin depth. So, we know that skin depth is given by $\frac{1}{\sqrt{\pi f \mu \sigma}}$. Then we can write this as $\frac{1}{\sqrt{\pi f \mu_r \mu_0 \sigma_c}}$ in place of μ we can write $\mu_r \mu_0$ and in place of σ we can write σ_c . So, this if we put the values π we know μ_r we know $4\pi \times 10^{-7}$ σ_c I have given in the last class that 5.8×10^7 . If you put all these values it will come as 0.06609 by root over $\mu_r \sigma_c$ and f and the unit will be m meter. This is the skin depth so unit will be meter.

LECTURE 52: SE DUE TO FARFIELD SOURCES (CONTD. 2)
AND
FREE SPACE IMPEDANCE AT NEARFIELD

$$A(\text{dB}) = 20 \log_{10} e^{-t/\delta}$$
$$\delta = \frac{1}{\sqrt{\pi f \mu \sigma}}$$
$$= \frac{1}{\sqrt{\pi f \mu_r \mu_0 \sigma_c}}$$
$$= \frac{0.06609}{\sqrt{\mu_r \sigma_c f}} \text{ m}$$

So, if we put that in a t b expression. So, a t b is 20 log 10. So, let me bring that t by delta 20 t by delta log 10 e is log 10 e is 8.6859 that multiplied with 20 that will be 8.6859 t by delta. So 28.6859 that t will give and delta expression will put 0.06609 and root over mu r sigma r f where t is in meter, but that is generally unusual the thickness. So, if we put it in or, but you will have to properly take the unit. So, if you do this calculation it is 131.4 t into mu r f again to remind that t is in meter it is written. So, you see that absorption loss unlike reflection loss that increases with frequency and you can also note that reflection loss was a function of sigma r by mu r, but absorption loss is a function of sigma r into mu r. So, for far field sources we can draw the conclusion for far field sources our conclusion is that reflection loss reflection loss is the predominant shielding mechanism of the reflection loss at lower frequencies and absorption loss is the predominant shielding mechanism at higher frequencies. That means, absorption loss is due to the travel of the wave through the shield reflection loss is whatever gets reflected at the boundaries. So, that this is an insight which came after we derived the expressions. So, this will be helpful that where you are trying to make shielding affecting at what frequency. So, what you should see whether you will try to adjust the reflection loss or try to adjust the absorption loss that is an good insight these two lines giving.

$$A_{dB} = 20 \frac{t}{\delta} \log_{10} e$$

$$= 8.6859 \frac{t}{\delta}$$

$$= \frac{8.6859}{0.06609} t \sqrt{\mu_r \sigma_r} \quad (t \text{ in m})$$

$$= 131.4 t \sqrt{\mu_r \sigma_r} \quad (t \text{ in m})$$

For farfield sources

- Reflection loss is the predominant shielding mechanism at lower frequencies
- Absorption loss is the predominant shielding mechanism at higher frequencies

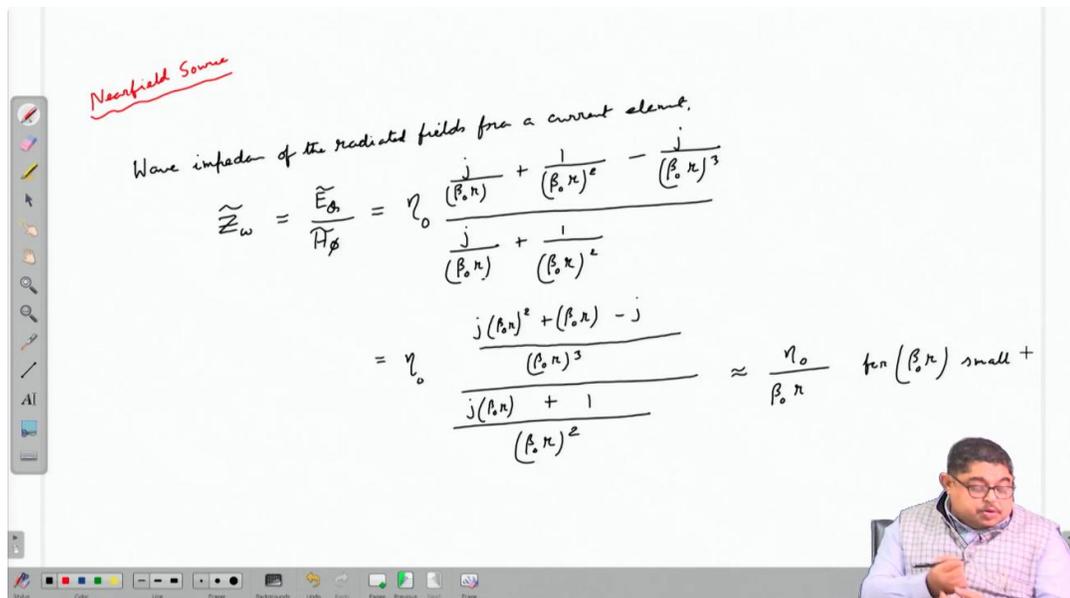
Now, let us switch over to the discussion on near field sources. As I already said that in EMC cases they were very common because from a nearby circuit from a nearby oscillator it may come that may not have sufficient distance to call far field. So, now there let us start the discussion with a hertzian dipole or a current element. Now already while finding radiated emission we have discussed this elemental radiator. So, we know it is field well. So, what is the wave impedance? Wave impedance of the radiated fields from a current element. So, let us call that z wave that is we know that E theta by h phi is

wave impedance also we can say E_θ by h_θ etcetera. So, there are with any coordinate there are three directed wave impedances. So, let us take this one that expression if you look at the that time gave you the expressions exact expressions of fields not with far field approximation the field expression it will be E_θ by h_θ will be J by $\beta_0 r$ plus 1 by $\beta_0 r$ square minus J by $\beta_0 r$ cube divided by for h_θ there will be J by $\beta_0 r$ plus 1 by $\beta_0 r$ whole square. So, if I simplify this it will be η_0 . So, the numerator the highest order term is η_0 cube. So, let me write $J \beta_0 r$ square plus $\beta_0 r$ minus J and in the denominator the highest term is $\beta_0 r$ square. So, it will give you $J \beta_0 r$ plus 1 . So, that will be roughly if you consider that $\beta_0 r$ is much smaller that means, A is not at the source and the receptor are not very far $\beta_0 r$ is small you will get that it is η_0 by $\beta_0 r$ or $\beta_0 r$ is small.

Nearfield Source

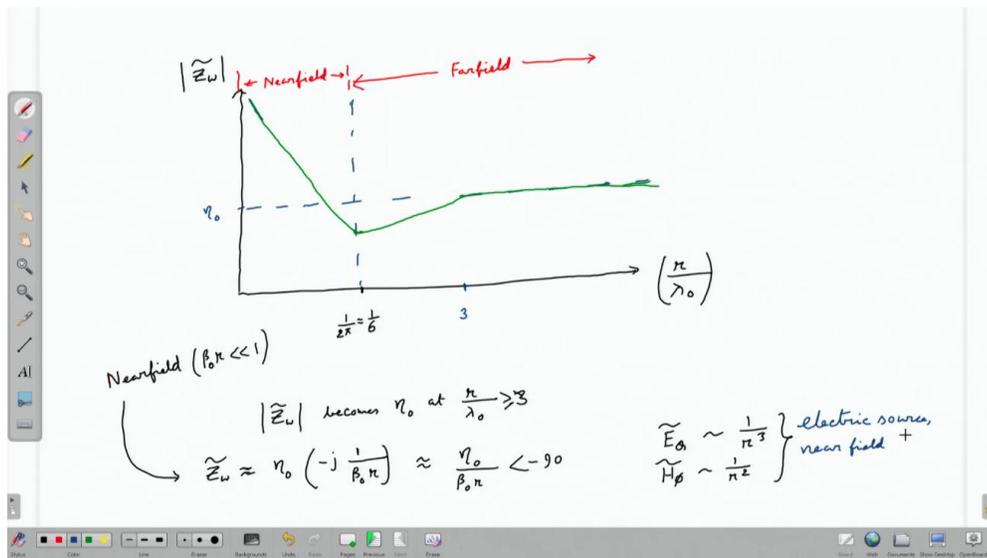
Wave impedance of the radiated fields from a current element.

$$\tilde{Z}_w = \frac{\tilde{E}_\theta}{H_\phi} = \eta_0 \frac{\frac{j}{(\beta_0 r)} + \frac{1}{(\beta_0 r)^2} - \frac{j}{(\beta_0 r)^3}}{\frac{j}{(\beta_0 r)} + \frac{1}{(\beta_0 r)^2}}$$

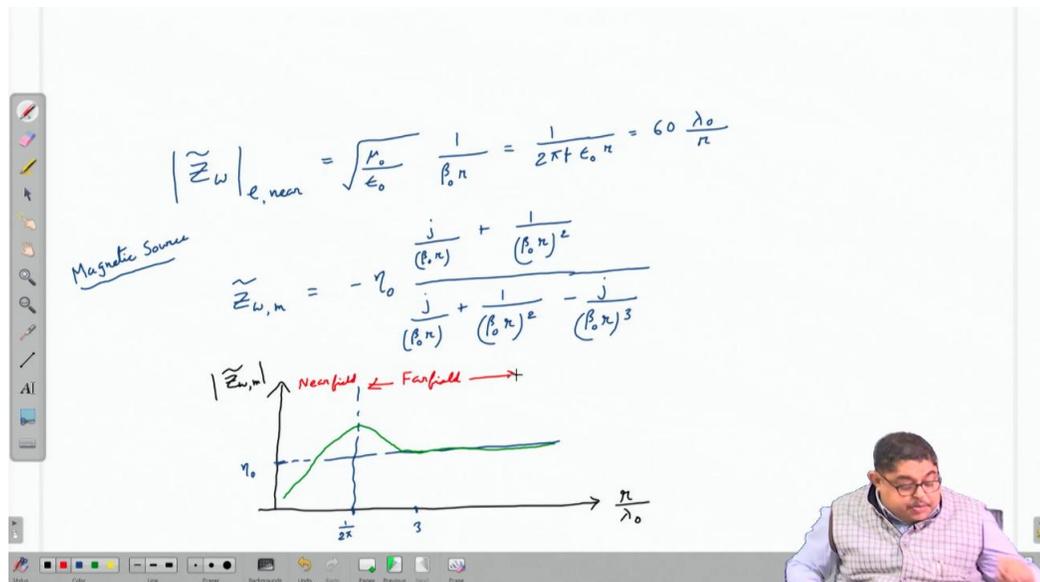
$$= \eta_0 \frac{j(\beta_0 r)^2 + (\beta_0 r) - j}{(\beta_0 r)^3} \approx \frac{\eta_0}{\beta_0 r} \text{ for } (\beta_0 r) \text{ small}$$


And so we can draw this as the magnitude versus r by $\lambda \beta_0$ is actually 2π by λ . So, that 2π you will have this and if I draw a line at 1 by 2π roughly is equal to 1 by 6 you can say. And then the impedance sorry if you plot it comes like this. So, this is the impedance in free space. So actually we can say roughly this is the near field. And this is the far field that means, r is equal to λ by 2π that is the boundary between near field and a field. So, you can see that the near field when $\beta_0 r$ is much greater than 1 , well less than 1 near field is when $\beta_0 r$ is much less than 1 . So, when we are much less the impedance free space impedance or wave impedance of the wave generated by a current element it is having a very high value much much above the intrinsic impedance of free space. So see now if you

increase the distance it is coming down at a distance of r by λ η is equal to 1 by 2π it comes below the 277 ohm value. Then if you increase further it goes and roughly at r is equal to 3λ η it becomes equal to η and thereafter it stays there that means, in throughout the after these distances if you go on increasing the distances the wave impedance is constant. So, we can say that Z_w becomes η at r by λ η greater than greater than equal to 3 . Now in the near field here what is ωZ I mean wave is roughly you can see it is η from the expression I have given it will be evident that when you have βr is much less than 1 . So, this term will prevalent so you have $\eta \sin \beta r$ and this is you can write as $\eta \sin \beta r$ minus 90 degree. So, impedance has a value $\eta \sin \beta r$ in the near field and its phase is minus 90 degree. Also we can see that in this near field E_θ that is varying as 1 by r^3 and H_ϕ that is varying as 1 by r^2 . This also is evident from this expressions that this one is electric field E_θ for H_ϕ it is 1 by r^2 . So, we can say that this is for electric source near field we are calling electric source because this is the case of a current element and almost all the radiators they are superposition of these. So, this type is maintained for any radiator which have conduction current on it and it radiates. Also, this current element or electric dipole or this electric sources they are called high impedance source. Why? Because you see that in the near field their impedance is much higher, wave impedance is much higher than the intrinsic impedance of free space that is why they are called high impedance source in cross talk analysis we have seen what is a high impedance source. So, here this is an example.



Now, let us convert this impedance into the material constants by including that. So, we can write it like this Z_{ω} electric source near that means in the near field this is our expression was η_0 by $\beta_0 r$. So, η_0 is root over μ_0 by ϵ_0 by $\beta_0 r$ that is you can easily find bring frequency here by β_0 is 2π by λ_0 . So, λ_0 can be converted as f and v , v is the velocity applied. So, if you do that it will come 1 by $2\pi f \epsilon_0 r$. So, this if you from f if you go to λ_0 you can easily go by knowing that it is electromagnetic wave travels if the velocity applied. So, you can write this as $60 \frac{\lambda_0}{r}$ is the near field value of an electric source. Now, let us consider a magnetic source. Magnetic source, so an elemental magnetic dipole that is a loop that is a elemental magnetic dipole. So, consider that we will find its field then we will find its wave impedance. Now it is basically dual of the electric field. So, if we use the principle of duality or you can actually probably in antenna classes you have derived it from the basic principles. So, in antenna books this expression is given. So, I am just writing the expression that will be a minus sign will come and j by $\beta_0 r$ plus 1 by $\beta_0 r$ square divided by j by $\beta_0 r$ plus 1 by $\beta_0 r$ whole square minus j by $\beta_0 r$ whole cube. So, if we draw this, this is j u magnitude, this is r by λ_0 . So, this is r by λ_0 . Same type of thing, only thing it is very low in the near field. So, roughly you can say this is the near field, this is the far field. So, in the near field the impedance is very smaller, very much small compared to η_0 that means free space impedance, but it at the near field, far field boundary it overshoots η_0 , then it comes down and by at a distance r by λ_0 is equal to 3 , it comes to the value of η_0 .



So, we can say that $j\omega m$ is minus $j\eta_0 \beta_0 r$, this from the expression given you can easily find. So, this is $\eta_0 \beta_0 r$ minus 90 degree. So, we can say that h_θ is proportional to $1/r^3$ E_ϕ is proportional to $1/r^2$ for magnetic sources near field. So, magnetic dipole is referred to as a low impedance source for obvious reasons. Now, what is the magnitude of this in terms of the parameters? So, we can write $j\omega m$ is equal to $2\pi f \mu_0 r$ is equal to $2369 r / \lambda_0$. Now example of a magnetic source is a transformer. So, if you have a transformer in the circuit, you will get the in the near field the wave will be having this type of variation. Electric source is a process of a DC motor spark gap, they are the example of electric sources or any antenna radiating. So, this electric source and magnetic source will have to see them separately because their impedances are different, one is a high impedance another is low impedance. So, their shielding effectiveness will also be different. So, separately we will have to consider. In far field there was no separation because far field is a stable zone where we already got a fixed impedance that that impedance we take as η_0 , but here in the near field we cannot do that. So, when we saw deeper we saw that the impedances one is a high impedance, there are high impedance case there is low impedance case. So, for that we need to find shielding effectiveness for both of them separately that we will do in the next class. Thank you.

The whiteboard contains the following handwritten notes:

$$\tilde{Z}_{\omega,m} \approx -j\eta_0 \beta_0 r$$

$$= \eta_0 \beta_0 r \angle -90^\circ$$

$H_\theta \sim \frac{1}{r^3}$
 $E_\phi \sim \frac{1}{r^2}$

} Magnetic source, nearfield.

$$\tilde{Z}_{\omega,m} = 2\pi f \mu_0 r$$

$$= 2369 \frac{r}{\lambda_0}$$

The lecturer, a man with glasses wearing a purple shirt, is visible in the bottom right corner of the video frame.